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2N3418

#### **APPLICATIONS:**

- Power Supply
- Pulse Amplifier
- High Frequency Power Switching

#### **FEATURES:**

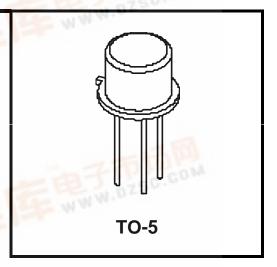
- Meets MIL-S-19500/393
- Collector-Base Voltage: up to 85V
- Peak Collector Current: 5A
- High Power Dissipation in TO-5: 15W @ T<sub>C</sub> = 100°C
- Fast Switching

3 Amp, 85V, NPN Silicon Power Transistors JAN, JTX, JTXV, JANS

#### **DESCRIPTION:**

These power transistors are produced by PPC's DOUBLE DIFFUSED PLANAR process. This technology produces high voltage devices with excellent switching speeds, frequency response, gain linearity, saturation voltages, high current gain, and safe operating areas. They are intended for use in Commercial, Industrial, and Military power switching, amplifier, and regulator applications.

Ultrasonically bonded leads and controlled die mount techniques are utilized to further increase the SOA capability and inherent reliability of these devices. The temperature range to 200°C permits reliable operation in high ambients, and the hermetically sealed package insures maximum reliability and long life.



#### **ABSOLUTE MAXIMUM RATINGS:**

SYMBOL	CHARACTERISTIC	VALUE	UNITS
V <sub>CBO</sub> *	Collector-Base Voltage	85	Volts
$V_{CEO}^*$	Collector-Emitter Voltage	60	Volts
$V_{EBO}^*$	Emitter-Base Voltage	8	Volts
l <sub>c</sub> *	D.C. Collector Current	3	Amps
l <sub>C</sub> *	Peak Collector Current	5	Amps
T <sub>STG</sub> *	Storage Temperature	-65 to 200	∘C
T <sub>J</sub> *	Operating Junction Temperature	-65 to 200	۰C
P <sub>T</sub> *	Power Dissipation  T <sub>C</sub> = 25°C Ambient	1.0	Watts
	T <sub>C</sub> = 100°C Case	15	Watts

Indicates MIL-S-19500/393



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# **ELECTRICAL CHARACTERISTICS:** (25°Case Temperature Unless Otherwise Noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	VAI	VALUE	
		TEST CONDITIONS	Min.	Max.	Units
BV <sub>CEO*</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50 mAdc, Cond. D (Note 1)	60		Vdc
I <sub>CEX</sub> *	Collector-Emitter Cutoff Current	V <sub>EB</sub> = 0.5 Vdc, Cond. A, V <sub>CE</sub> = 80 Vdc		0.3	μ <b>Ad</b>
		$V_{EB} = 0.5 \text{ Vdc}$ , Cond. A, $T_A = 150$ °C, $V_{CE} = 80 \text{ Vdc}$		50	μ <b>Ad</b>
I <sub>CEO*</sub>	Collector-Emitter Cutoff Current	V <sub>CE</sub> = 45 Vdc, Cond. D		5.0	μ <b>Ad</b>
I <sub>EBO</sub> *	Emitter-Base	V <sub>EB</sub> = 6 Vdc, Cond. D		0.5	μ <b>Ad</b>
	Cutoff Current	V <sub>EB</sub> = 8 Vdc, Cond. D		10	μ <b>Ad</b>
hFE*	D.C. Current Gain (Note 1)	$I_C = 100 \text{ mAdc}, V_{CE} = 2 \text{ Vdc}$	20		
		$I_C = 1$ Adc, $V_{CE} = 2$ Vdc	20	60	
		$I_C = 2 \text{ Adc}, V_{CE} = 2 \text{ Vdc}$	15		
		$I_C = 5$ Adc, $V_{CE} = 5$ Vdc	10		
		$I_C = 1 \text{ Adc}, V_{CE} = 2 \text{ Vdc}, T_A = -55^{\circ}C$	10		
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage (Note 1)	I <sub>C</sub> = 1 Adc, I <sub>B</sub> = 0.1 Adc		0.25	Vd
		$I_C = 2 \text{ Adc}, I_B = 0.2 \text{ Adc}$		0.5	Vd
V <sub>BE(sat)*</sub>	Base-Emitter Saturation Voltage (Note 1)	I <sub>C</sub> = 1 Adc, I <sub>B</sub> = 0.1 Adc	0.6	1.2	Vd
		$I_C = 2 \text{ Adc}, I_B = 0.2 \text{ Adc}$	0.7	1.4	Vd
I <sub>S/b*</sub>	Forward Biased Second Breakdown	V <sub>CE</sub> = 5 Vdc, T <sub>C</sub> = 100°C	3		Ad
		V <sub>CE</sub> = 37 Vdc, T <sub>C</sub> = 100°C	0.4		Ad
		V <sub>CE</sub> = 60 Vdc, T <sub>C</sub> = 100°C	185		mA
E <sub>S/b*</sub>	Unclamped Reverse Biased Second Breakdown	I <sub>C</sub> = 3 Adc, L = 10 mH, Base Open	45		m
E <sub>S/b*</sub>	clamped Reverse Biased Second Breakdown	I <sub>C</sub> = 3 Adc, L = 40 mH, V <sub>Clamp</sub> = 85V	180		m
f <sub>T</sub> *	Gain Bandwidth Product	I <sub>C</sub> = 0.1 Adc, V <sub>CE</sub> = 10 Vdc, f = 20 MHz	26	160	МН
C <sub>Ob</sub> *	Output Capacitance	V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1 MHz		150	pf
t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 1 Adc, I <sub>B1</sub> = - I <sub>B2</sub> = 0.1 Adc		0.3	μS
t <sub>off</sub>	Turn-off Time	I <sub>C</sub> = 1 Adc, I <sub>B1</sub> = - I <sub>B2</sub> = 0.1 Adc		1.2	μS
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Note 1: Pulse Test: Pulse width =  $300\mu Sec.$ , duty cycle  $\leq 2\%$ .

<sup>\*</sup> Indicates MIL-S-19500/393



## 2N3418

### **PACKAGE MECHANICAL DATA:**

